NSN 5961-00-566-3706



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-566-3706 **Inclosure Material:** Metal **Overall Length:** 0.449 inches **Overall Diameter:** 0.648 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Item must comply with requirements of desc producton standard no. L01656; for navy nuclear propulsion plant products only; junction pattern arrangement: npn **Thread Series Designator:** Unf

Unit Of Measure:

3 tab, solder lug Shelf Life:

Terminal Type And Quantity:

N/a

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No

Fiig:

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